

74LVC1G384

Bilateral switch

Rev. 01 — 26 February 2004

Product data sheet

1. General description

The 74LVC1G384 is a high-speed Si-gate CMOS device.

The 74LVC1G384 provides an analog switch. The switch has input and output terminals (pins Y and Z) and an active LOW enable input (pin \bar{E}). When pin \bar{E} is HIGH, the analog switch is turned off.

2. Features

- Very low ON-resistance:
 - ◆ 7.5 Ω (typ) at $V_{CC} = 2.7$ V
 - ◆ 6.5 Ω (typ) at $V_{CC} = 3.3$ V
 - ◆ 6.0 Ω (typ) at $V_{CC} = 5$ V.
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-A exceeds 2 000 V
 - ◆ MM EIA/JESD22-A115-A exceeds 200 V.
- High noise immunity
- CMOS low power consumption
- Direct interface TTL-levels
- Latch-up performance meets requirements of JESD78 Class I
- Multiple package options
- Specified from -40 °C to $+80$ °C and -40 °C to $+125$ °C.

3. Quick reference data

Table 1: Quick reference data

Ground = 0 V; $T_{amb} = 25$ °C; $t_r = t_f \leq 3.0$ ns.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------|---------------------------|---|-----|------------|-----|----------|
| t_{PZH}, t_{PZL} | turn-on time E to Y or Z | $C_L = 50$ pF; $R_L = 500$ Ω $V_{CC} = 3.3$ V $V_{CC} = 5.0$ V | - | 4.8 3.3 | - | ns ns |
| t_{PHZ}, t_{PLZ} | turn-off time E to Y or Z | $C_L = 50$ pF; $R_L = 500$ Ω $V_{CC} = 3.3$ V $V_{CC} = 5.0$ V | - | 5.4 3.6 | - | ns ns |
| C_i | input capacitance | | - | 2 | - | pF |

Table 1: Quick reference data ...continued

Ground = 0 V; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $t_r = t_f \leq 3.0\text{ ns}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------|-------------------------------|---|--------------|------|-----|------|
| C_{PD} | power dissipation capacitance | $C_L = 50\text{ pF}$; $f_i = 10\text{ MHz}$; $V_{CC} = 3.3\text{ V}$ | [1] - [2] | 15.2 | - | pF |
| C_S | switch capacitance | OFF-state | - | 5 | - | pF |
| | | ON-state | - | 9.5 | - | pF |

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + (C_L + C_S) \times V_{CC}^2 \times f_o \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

C_S = maximum switch capacitance in pF;

V_{CC} = supply voltage in V.

[2] The condition is $V_i = \text{GND to } V_{CC}$.

4. Ordering information

Table 2: Ordering information

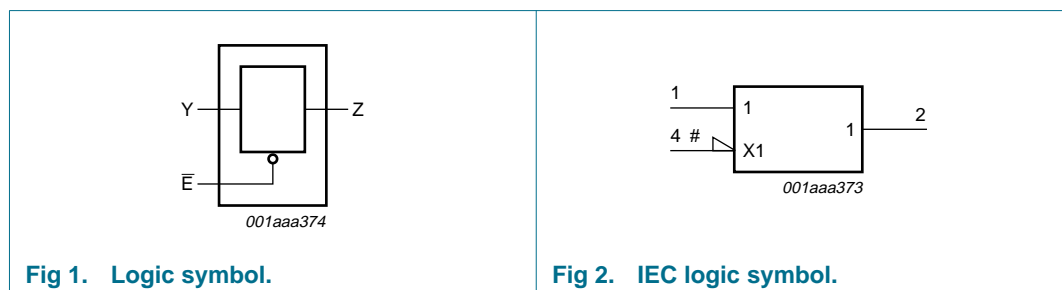
| Type number | Package | | | Version |
|--------------|-------------------|------|--|---------|
| | Temperature range | Name | Description | |
| 74LVC1G384GW | -40 °C to +125 °C | - | plastic surface mounted package; 5 leads | SOT353 |
| 74LVC1G384GV | -40 °C to +125 °C | - | plastic surface mounted package; 5 leads | SOT753 |

5. Marking

Table 3: Marking

| Type number | Marking code |
|--------------|--------------|
| 74LVC1G384GW | YL |
| 74LVC1G384GV | YL |

6. Functional diagram



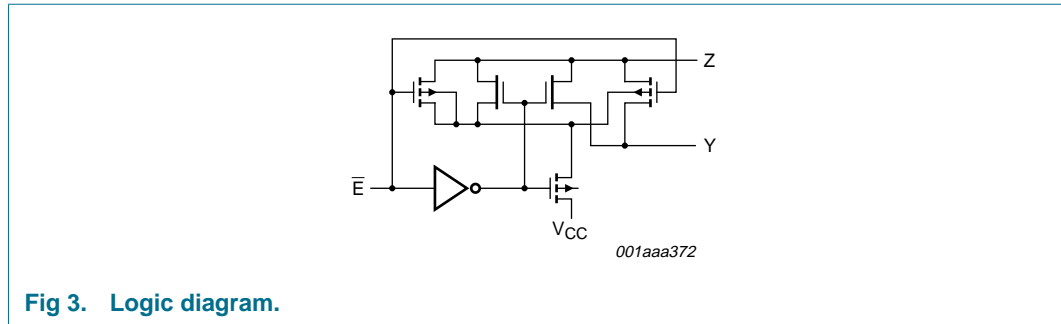


Fig 3. Logic diagram.

7. Pinning information

7.1 Pinning

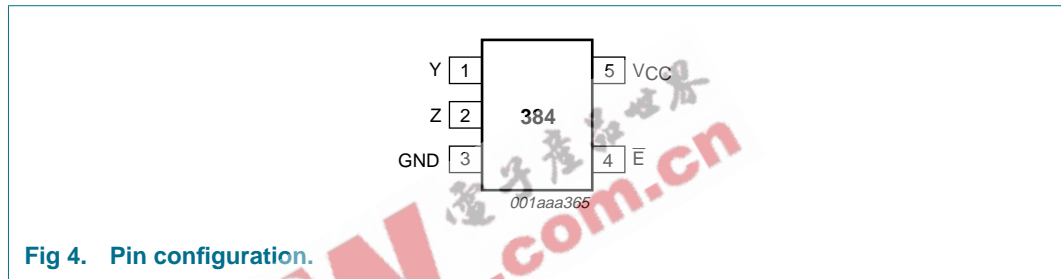


Fig 4. Pin configuration.

7.2 Pin description

Table 4: Pin description

| Pin | Symbol | Description |
|-----|-----------------|-----------------------------|
| 1 | Y | independent input or output |
| 2 | Z | independent output or input |
| 3 | GND | ground (0 V) |
| 4 | \bar{E} | enable input (active LOW) |
| 5 | V _{CC} | supply voltage |

8. Functional description

8.1 Function table

Table 5: Function table [1]

| Input \bar{E} | Switch |
|-----------------|-----------|
| L | ON-state |
| H | OFF-state |

[1] H = HIGH voltage level;
L = LOW voltage level.

9. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|----------------------------------|---|----------|----------------|--------------------|
| V_{CC} | supply voltage | | -0.5 | +6.5 | V |
| V_I | input voltage | | [1] -0.5 | +6.5 | V |
| I_{IK} | input diode current | $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V | - | -50 | mA |
| I_{SK} | switch diode current | $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V | - | ± 50 | mA |
| V_S | DC switch voltage range | enable and disable mode | -0.5 | $V_{CC} + 0.5$ | V |
| I_S | DC switch source or sink current | $V_S > -0.5$ V or $V_S < V_{CC} + 0.5$ V | - | ± 50 | mA |
| I_{CC}, I_{GND} | V_{CC} or GND current | | - | ± 100 | mA |
| T_{stg} | storage temperature | | -65 | +150 | $^{\circ}\text{C}$ |
| P_{tot} | power dissipation | $T_{amb} = -40$ $^{\circ}\text{C}$ to $+125$ $^{\circ}\text{C}$ | - | 250 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 7: Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------|---------------------------|----------------------------|-------|-----|----------|--------------------|
| V_{CC} | supply voltage | | 1.65 | - | 5.5 | V |
| V_I | input voltage | | 0 | - | 5.5 | V |
| V_S | DC switch voltage range | | [1] 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | - | +125 | $^{\circ}\text{C}$ |
| t_r, t_f | input rise and fall times | $V_{CC} = 1.65$ V to 2.7 V | 0 | - | 20 | ns/V |
| | | $V_{CC} = 2.7$ V to 5.5 V | 0 | - | 10 | ns/V |

[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminal Y. In this case there is no limit for the voltage drop across the switch.

11. Static characteristics

Table 8: Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|---|---|--|------------------------|------|------------------------|------|--|
| T_{amb} = -40 °C to +85 °C [1] | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 1.65 V to 1.95 V | 0.65 × V _{CC} | - | - | V | |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | V | |
| | | V _{CC} = 2.7 V to 3.6 V | 2.0 | - | - | V | |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7 × V _{CC} | - | - | V | |
| V _{IL} | LOW-level input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.35 × V _{CC} | V | |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V | |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | V | |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 0.3 × V _{CC} | V | |
| I _{LI} | input leakage current on control pin | V _I = 5.5 V or GND; V _{CC} = 5.5 V | [2] - | ±0.1 | ±5 | µA | |
| I _{S(OFF)} | analog switch OFF-state current | V _I = V _{IH} or V _{IL} ; V _S = V _{CC} - GND; V _{CC} = 5.5 V; see Figure 5 | [2] - | ±0.1 | ±5 | µA | |
| I _{S(ON)} | analog switch ON-state current | V _I = V _{IH} or V _{IL} ; V _S = V _{CC} - GND; V _{CC} = 5.5 V; see Figure 6 | [2] - | ±0.1 | ±5 | µA | |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; V _S = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V | [2] - | 0.1 | 10 | µA | |
| ΔI _{CC} | additional quiescent supply current per control pin | V _I = V _{CC} - 0.6 V; V _S = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V | [2] - | 5 | 500 | µA | |
| C _I | input capacitance | | - | 2 | - | pF | |
| R _{ON(peak)} | switch ON-state resistance (peak) | V _I = GND to V _{CC} ; see Figure 7 and Figure 8 | | | | | |
| | | I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V | - | 35 | 130 | Ω | |
| | | I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V | - | 14 | 30 | Ω | |
| | | I _S = 12 mA; V _{CC} = 2.7 V | - | 11.5 | 25 | Ω | |
| | | I _S = 24 mA; V _{CC} = 3.0 V to 3.6 V | - | 8.5 | 20 | Ω | |
| | | I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V | - | 6.5 | 15 | Ω | |
| R _{ON(rail)} | switch ON-state resistance rail | V _I = GND | | | | | |
| | | I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V | - | 10 | 30 | Ω | |
| | | I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V | - | 8.5 | 20 | Ω | |
| | | I _S = 12 mA; V _{CC} = 2.7 V | - | 7.5 | 18 | Ω | |
| | | I _S = 24 mA; V _{CC} = 3.0 V to 3.6 V | - | 6.5 | 15 | Ω | |
| | | I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V | - | 6 | 10 | Ω | |
| | | V _I = V _{CC} | | | | | |
| | | I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V | - | 12 | 30 | Ω | |
| | | I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V | - | 8.5 | 20 | Ω | |
| | | I _S = 12 mA; V _{CC} = 2.7 V | - | 7.5 | 18 | Ω | |
| | | I _S = 24 mA; V _{CC} = 3.0 V to 3.6 V | - | 6.5 | 15 | Ω | |
| | | I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V | - | 6 | 10 | Ω | |

Table 8: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|---|--|----------------------|-----|----------------------|---------------|
| $R_{ON(Flat)}$ | switch ON-state resistance flatness | $V_I = \text{GND to } V_{CC}$; see Figure 9 | [3] | | | |
| | | $I_S = 4 \text{ mA}; V_{CC} = 1.8 \text{ V}$ | - | 100 | - | Ω |
| | | $I_S = 8 \text{ mA}; V_{CC} = 2.5 \text{ V}$ | - | 17 | - | Ω |
| | | $I_S = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$ | - | 10 | - | Ω |
| | | $I_S = 24 \text{ mA}; V_{CC} = 3.3 \text{ V}$ | - | 5 | - | Ω |
| | | $I_S = 32 \text{ mA}; V_{CC} = 5.0 \text{ V}$ | - | 3 | - | Ω |
| $T_{amb} = -40 \text{ }^\circ\text{C to } +125 \text{ }^\circ\text{C}$ | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | $0.65 \times V_{CC}$ | - | - | V |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 1.7 | - | - | V |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 2.0 | - | - | V |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | $0.7 \times V_{CC}$ | - | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | - | - | $0.35 \times V_{CC}$ | V |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | - | 0.7 | V |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | - | 0.8 | V |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | - | - | $0.3 \times V_{CC}$ | V |
| I_{LI} | input leakage current on control pin | $V_I = 5.5 \text{ V or GND}; V_{CC} = 5.5 \text{ V}$ | - | - | 100 | μA |
| $I_{S(OFF)}$ | analog switch OFF-state current | $V_I = V_{IH} \text{ or } V_{IL}; V_S = V_{CC} - \text{GND}; V_{CC} = 5.5 \text{ V};$ see Figure 5 | - | - | 200 | μA |
| $I_{S(ON)}$ | analog switch ON-state current | $V_I = V_{IH} \text{ or } V_{IL}; V_S = V_{CC} - \text{GND}; V_{CC} = 5.5 \text{ V};$ see Figure 6 | - | - | 200 | μA |
| I_{CC} | quiescent supply current | $V_I = V_{CC} \text{ or GND}; V_S = \text{GND or } V_{CC}; I_O = 0 \text{ A}; V_{CC} = 5.5 \text{ V}$ | - | - | 200 | μA |
| ΔI_{CC} | additional quiescent supply current per control pin | $V_I = V_{CC} - 0.6 \text{ V}; V_S = \text{GND or } V_{CC}; I_O = 0 \text{ A}; V_{CC} = 5.5 \text{ V}$ | - | - | 5000 | μA |
| $R_{ON(peak)}$ | switch ON-state resistance (peak) | $V_I = \text{GND to } V_{CC}$; see Figure 7 | | | | |
| | | $I_S = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | - | - | 180 | Ω |
| | | $I_S = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | - | 45 | Ω |
| | | $I_S = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$ | - | - | 38 | Ω |
| | | $I_S = 24 \text{ mA}; V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | - | - | 30 | Ω |
| | | $I_S = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | - | - | 23 | Ω |

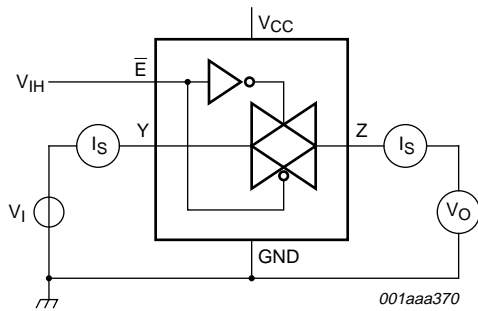
Table 8: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|----------------|---------------------------------|--|-----|-----|-----|----------|--|
| $R_{ON(rail)}$ | switch ON-state resistance rail | $V_I = GND$ | | | | | |
| | | $I_S = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | - | - | 45 | Ω | |
| | | $I_S = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | - | 30 | Ω | |
| | | $I_S = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$ | - | - | 27 | Ω | |
| | | $I_S = 24 \text{ mA}; V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | - | - | 23 | Ω | |
| | | $I_S = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | - | - | 15 | Ω | |
| | | $V_I = V_{CC}$ | | | | | |
| | | $I_S = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | - | - | 45 | Ω | |
| | | $I_S = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | - | 30 | Ω | |
| | | $I_S = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$ | - | - | 27 | Ω | |
| | | $I_S = 24 \text{ mA}; V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | - | - | 23 | Ω | |
| | | $I_S = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | - | - | 15 | Ω | |

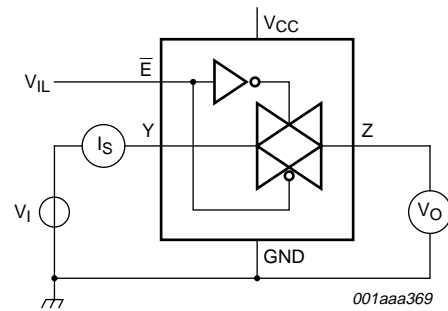
[1] Typical values are measured at $T_{amb} = 25 \text{ }^\circ\text{C}$.[2] These typical values are measured at $V_{CC} = 3.3 \text{ V}$ [3] These typical values are measured over the operating temperature range from $-40 \text{ }^\circ\text{C}$ to $+125 \text{ }^\circ\text{C}$.

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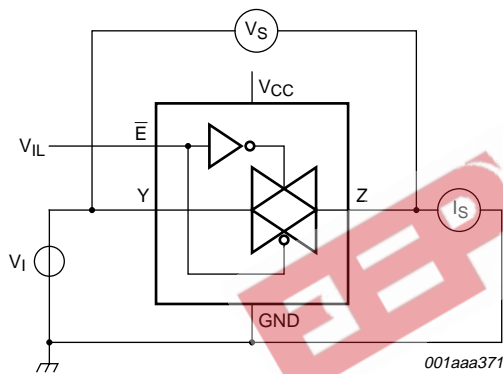
$V_I = V_{CC}$ and $V_O = GND$;
 $V_I = GND$ and $V_O = V_{CC}$

Fig 5. Test circuit for measuring switch OFF-state current.



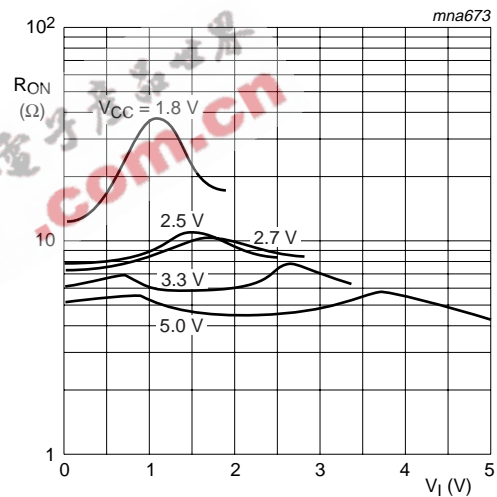
$V_I = V_{CC}$ and $V_O = \text{open circuit}$;
 $V_I = GND$ and $V_O = \text{open circuit}$

Fig 6. Test circuit for measuring switch ON-state current.



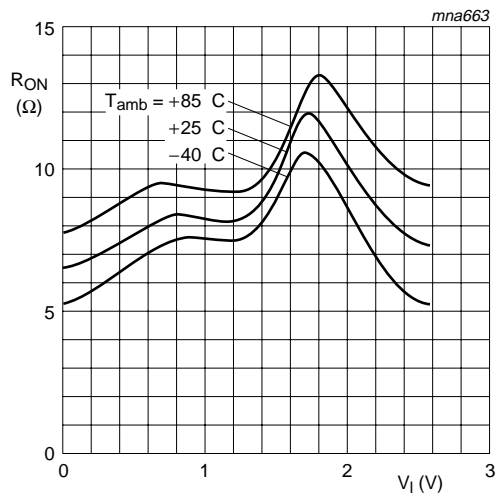
$V_I = GND$ to V_{CC} ; $R_{ON} = V_S/I_S$

Fig 7. Test circuit for measuring switch ON-resistance.

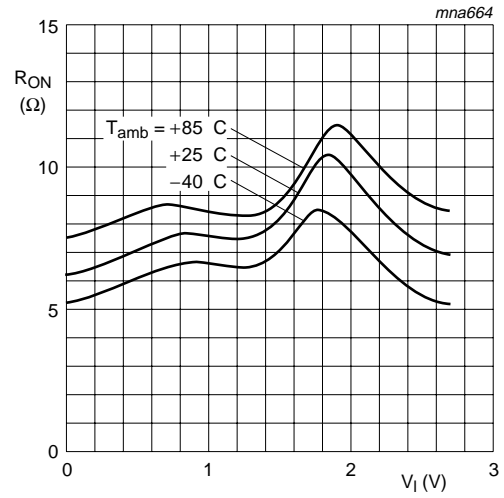


$V_S = GND$ to V_{CC} .

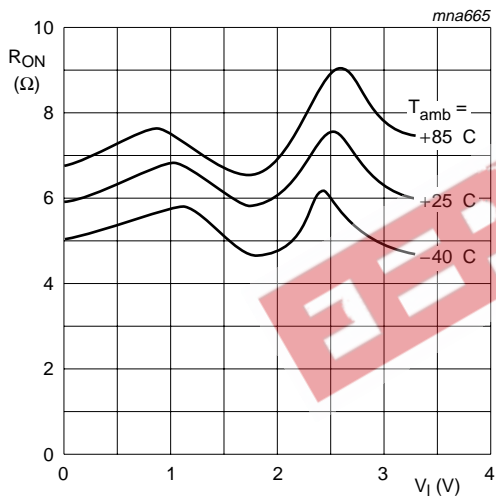
Fig 8. Typical switch ON-resistance as a function of input voltage.



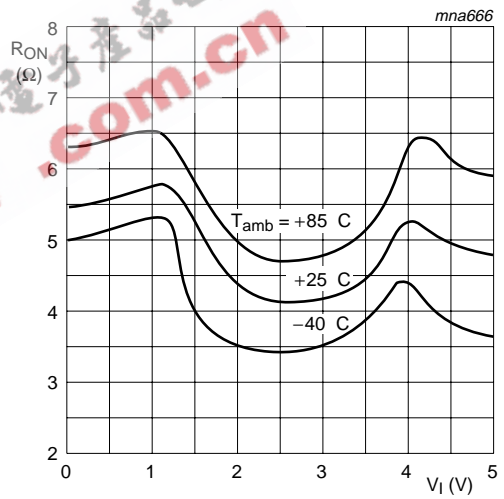
a. $V_{CC} = 2.5\text{ V}$



b. $V_{CC} = 2.7\text{ V}$



c. $V_{CC} = 3.3\text{ V}$



d. $V_{CC} = 5.0\text{ V}$

Fig 9. Switch ON-resistance at various supply voltages as a function of input voltage.

12. Dynamic characteristics

Table 9: Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); test circuit [Figure 12](#).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|------------------------------------|--|---------|------|------|------|
| $T_{amb} = -40\text{ °C to }+85\text{ °C}$ [1] | | | | | | |
| t_{PHL} , t_{PLH} | propagation delay Y to Z or Z to Y | see Figure 10 | [2] | | | |
| | | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | - | 0.8 | 2.0 | ns |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | - | 0.4 | 1.2 | ns |
| | | $V_{CC} = 2.7\text{ V}$ | - | 0.4 | 1.0 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | - | 0.3 | 0.8 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | - | 0.2 | 0.6 | ns |
| t_{PZH} , t_{PZL} | turn-on time \bar{E} to Y or Z | see Figure 11 | | | | |
| | | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | 1.0 | 10.0 | 12.0 | ns |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | 1.0 | 5.7 | 6.5 | ns |
| | | $V_{CC} = 2.7\text{ V}$ | 1.0 | 5.4 | 6.0 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.0 | 4.8 | 5.0 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | 1.0 | 3.3 | 4.2 | ns |
| t_{PHZ} , t_{PLZ} | turn-off time \bar{E} to Y or Z | see Figure 11 | | | | |
| | | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | 1.0 | 7.4 | 10.0 | ns |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | 1.0 | 4.1 | 6.9 | ns |
| | | $V_{CC} = 2.7\text{ V}$ | 1.0 | 4.9 | 7.5 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.0 | 5.4 | 6.5 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | 1.0 | 3.6 | 5.0 | ns |
| C_{PD} | power dissipation capacitance | $C_L = 50\text{ pF}$; $f_i = 10\text{ MHz}$; $V_I = \text{GND to }V_{CC}$ | [3] [4] | | | |
| | | $V_{CC} = 2.5\text{ V}$ | - | 13.7 | - | pF |
| | | $V_{CC} = 3.3\text{ V}$ | - | 15.2 | - | pF |
| | | $V_{CC} = 5.0\text{ V}$ | - | 18.3 | - | pF |
| $T_{amb} = -40\text{ °C to }+125\text{ °C}$ | | | | | | |
| t_{PHL} , t_{PLH} | propagation delay Y to Z or Z to Y | see Figure 10 | [2] | | | |
| | | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | - | - | 3.0 | ns |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | - | - | 2.0 | ns |
| | | $V_{CC} = 2.7\text{ V}$ | - | - | 1.5 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | - | - | 1.5 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | - | - | 1.0 | ns |
| t_{PZH} , t_{PZL} | turn-on time \bar{E} to Y or Z | see Figure 11 | | | | |
| | | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | 1.0 | - | 15.5 | ns |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | 1.0 | - | 8.5 | ns |
| | | $V_{CC} = 2.7\text{ V}$ | 1.0 | - | 8.0 | ns |
| | | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 1.0 | - | 6.5 | ns |
| | | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | 1.0 | - | 5.5 | ns |

Table 9: Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); test circuit [Figure 12](#).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------|-----------------------------------|--|-----|-----|------|------|
| t_{PHZ}, t_{PLZ} | turn-off time \bar{E} to Y or Z | see Figure 11 | | | | |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 1.0 | - | 13.0 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 1.0 | - | 9.0 | ns |
| | | $V_{CC} = 2.7 \text{ V}$ | 1.0 | - | 9.5 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 1.0 | - | 8.5 | ns |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 1.0 | - | 6.5 | ns |

- [1] All typical values are measured at $T_{amb} = 25 \text{ }^\circ\text{C}$.
- [2] t_{PHL} and t_{PLH} propagation delay is the calculated RC time constant of the typical switch ON-resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + (C_L + C_S) \times V_{CC}^2 \times f_o$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 C_L = output load capacitance in pF;
 C_S = maximum switch capacitance in pF;
 V_{CC} = supply voltage in V.
- [4] The condition is $V_I = \text{GND to } V_{CC}$.

13. Waveforms

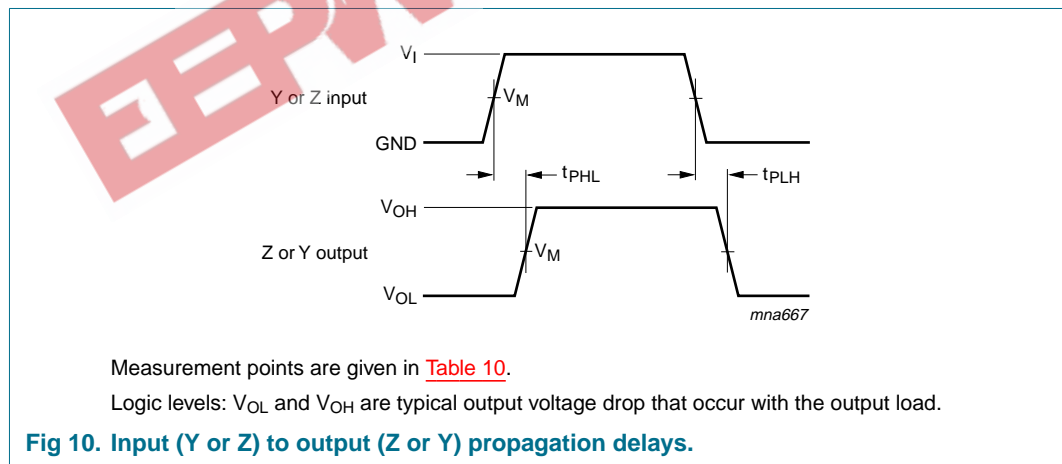


Table 10: Measurement points

| Supply voltage | Input | Output |
|------------------|---------------------|---------------------|
| V_{CC} | V_M | V_M |
| 1.65 V to 1.95 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 2.3 V to 2.7 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 2.7 V | 1.5 V | 1.5 V |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V |
| 4.5 V to 5.5 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |

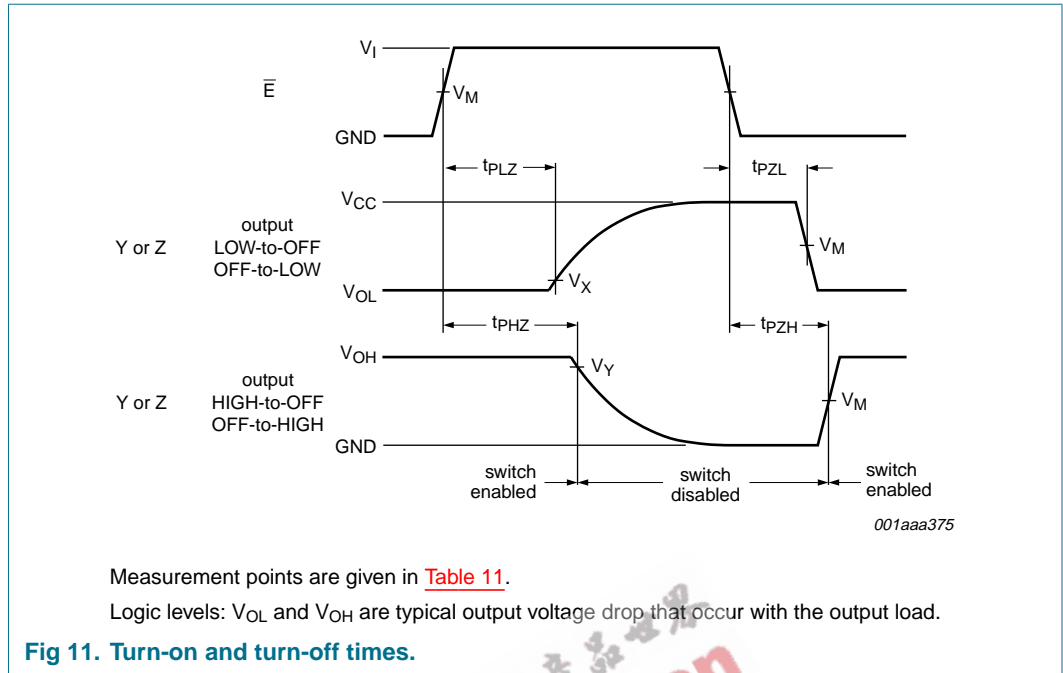


Table 11: Measurement points

| Supply voltage | Input | Output | | |
|------------------|---------------------|---------------------|------------------------------|------------------------------|
| V_{CC} | V_M | V_M | V_X | V_Y |
| 1.65 V to 1.95 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{OL} + 0.1 \times V_{CC}$ | $V_{OH} - 0.1 \times V_{CC}$ |
| 2.3 V to 2.7 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{OL} + 0.1 \times V_{CC}$ | $V_{OH} - 0.1 \times V_{CC}$ |
| 2.7 V | 1.5 V | 1.5 V | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |
| 4.5 V to 5.5 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |

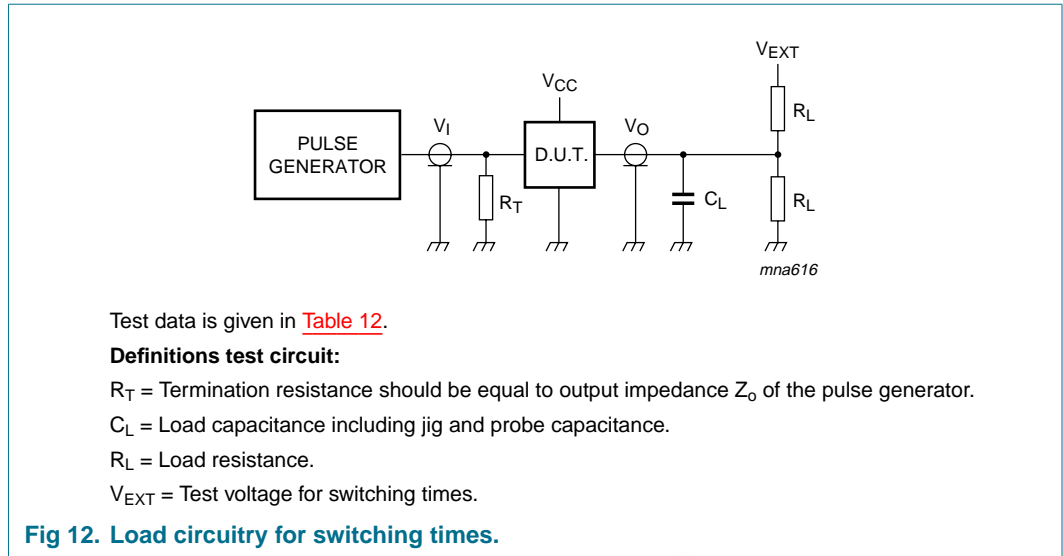


Table 12: Test data

| Supply voltage | Input | | Load | | V_{EXT} | | |
|------------------|----------|---------------|-------|--------------|--------------------|--------------------|--------------------|
| V_{CC} | V_I | t_r, t_f | C_L | R_L | t_{PLH}, t_{PHL} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 1.65 V to 1.95 V | V_{CC} | ≤ 2.0 ns | 30 pF | 1 k Ω | open | GND | $2 \times V_{CC}$ |
| 2.3 V to 2.7 V | V_{CC} | ≤ 2.0 ns | 30 pF | 500 Ω | open | GND | $2 \times V_{CC}$ |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 6.0 V |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 6.0 V |
| 4.5 V to 5.5 V | V_{CC} | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | $2 \times V_{CC}$ |

14. Additional dynamic characteristics

Table 13: Additional dynamic characteristics

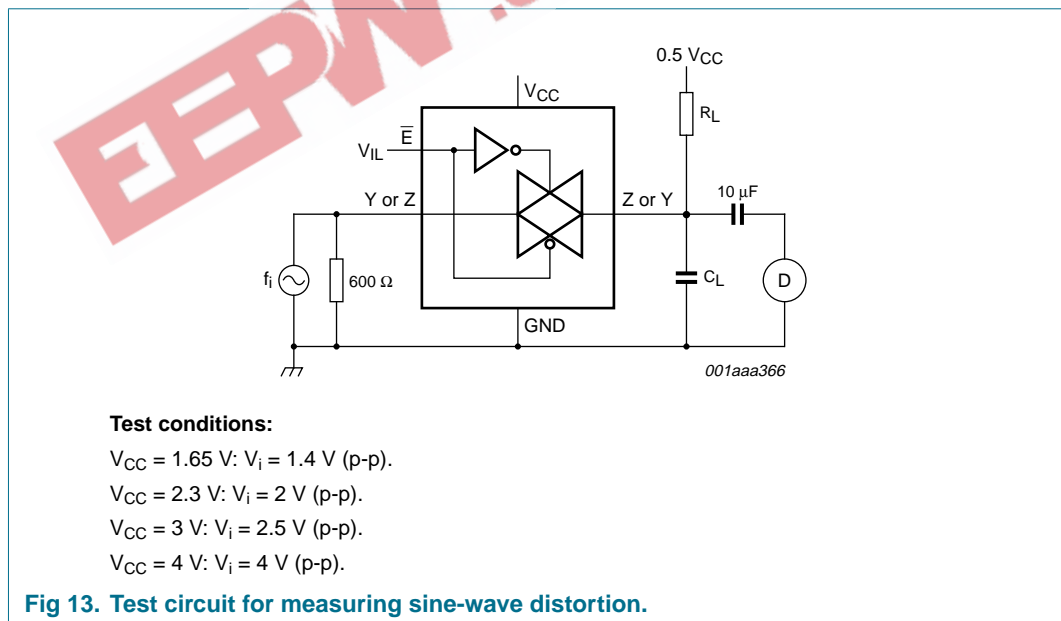
At recommended conditions; typical values measured at $T_{amb} = 25^\circ\text{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|----------------------------|--|---|-----|-------|-----|------|--|
| d_{sin} | sine-wave distortion | $f_i = 1\text{ kHz}$; $R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$; see Figure 13 | | | | | |
| | | $V_{CC} = 1.65\text{ V}$ | - | 0.032 | - | % | |
| | | $V_{CC} = 2.3\text{ V}$ | - | 0.008 | - | % | |
| | | $V_{CC} = 3.0\text{ V}$ | - | 0.006 | - | % | |
| | | $V_{CC} = 4.5\text{ V}$ | - | 0.001 | - | % | |
| | | $f_i = 10\text{ kHz}$; $R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$; see Figure 13 | | | | | |
| | | $V_{CC} = 1.65\text{ V}$ | - | 0.068 | - | % | |
| | | $V_{CC} = 2.3\text{ V}$ | - | 0.009 | - | % | |
| $f_{\text{ON-state(res)}}$ | switch ON-state signal frequency response | $R_L = 600\ \Omega$; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 14 | | | | | |
| | | $V_{CC} = 1.65\text{ V}$ | - | 135 | - | MHz | |
| | | $V_{CC} = 2.3\text{ V}$ | - | 145 | - | MHz | |
| | | $V_{CC} = 3.0\text{ V}$ | - | 150 | - | MHz | |
| | | $V_{CC} = 4.5\text{ V}$ | - | 155 | - | MHz | |
| | | $R_L = 50\ \Omega$; $C_L = 5\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 14 | [1] | | | | |
| | | $V_{CC} = 1.65\text{ V}$ | - | >500 | - | MHz | |
| | | $V_{CC} = 2.3\text{ V}$ | - | >500 | - | MHz | |
| $\alpha_{\text{OFF(ft)}}$ | switch OFF-state signal feed-through attenuation | $R_L = 600\ \Omega$; $C_L = 50\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 15 | | | | | |
| | | $V_{CC} = 1.65\text{ V}$ | - | -46 | - | dB | |
| | | $V_{CC} = 2.3\text{ V}$ | - | -46 | - | dB | |
| | | $V_{CC} = 3.0\text{ V}$ | - | -46 | - | dB | |
| | | $V_{CC} = 4.5\text{ V}$ | - | -46 | - | dB | |
| | | $R_L = 50\ \Omega$; $C_L = 5\text{ pF}$; $f_i = 1\text{ MHz}$; see Figure 15 | [2] | | | | |
| | | $V_{CC} = 1.65\text{ V}$ | - | -37 | - | dB | |
| | | $V_{CC} = 2.3\text{ V}$ | - | -37 | - | dB | |
| $V_{CC} = 3.0\text{ V}$ | - | -37 | - | dB | | | |
| $V_{CC} = 4.5\text{ V}$ | - | -37 | - | dB | | | |

Table 13: Additional dynamic characteristics ...continued
 At recommended conditions; typical values measured at $T_{amb} = 25^{\circ}C$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|--|--|-----|-----|------|------|
| V_{ct} | crosstalk between control input to signal output | $R_L = 600 \Omega$; $C_L = 50 \text{ pF}$; $f_i = 1 \text{ MHz}$; $t_r = t_f = 2 \text{ ns}$; see Figure 16 | - | 69 | - | mV |
| | | $V_{CC} = 1.65 \text{ V}$ | - | 87 | - | mV |
| | | $V_{CC} = 2.3 \text{ V}$ | - | 156 | - | mV |
| | | $V_{CC} = 3.0 \text{ V}$ | - | 302 | - | mV |
| f_{max} | frequency response (-3 dB) | $R_L = 50 \Omega$; $C_L = 10 \text{ pF}$; see Figure 14 | [1] | - | - | - |
| | | $V_{CC} = 1.65 \text{ V}$ | - | 200 | - | MHz |
| | | $V_{CC} = 2.3 \text{ V}$ | - | 350 | - | MHz |
| | | $V_{CC} = 3.0 \text{ V}$ | - | 410 | - | MHz |
| Q | injection charge | $C_L = 0.1 \text{ nF}$; $V_{gen} = 0 \text{ V}$; $R_{gen} = 0 \Omega$; $f = 1 \text{ MHz}$; $R_L = 1 \text{ M}\Omega$; $V_{CC} = 1.65 \text{ V}$ to 5.5 V ; see Figure 17 | [3] | - | 0.05 | pC |

- [1] Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.
- [2] Adjust f_i voltage to obtain 0 dBm level at input.
- [3] Definition: $Q = \Delta V_{out} \times C_L$. Guaranteed by design.



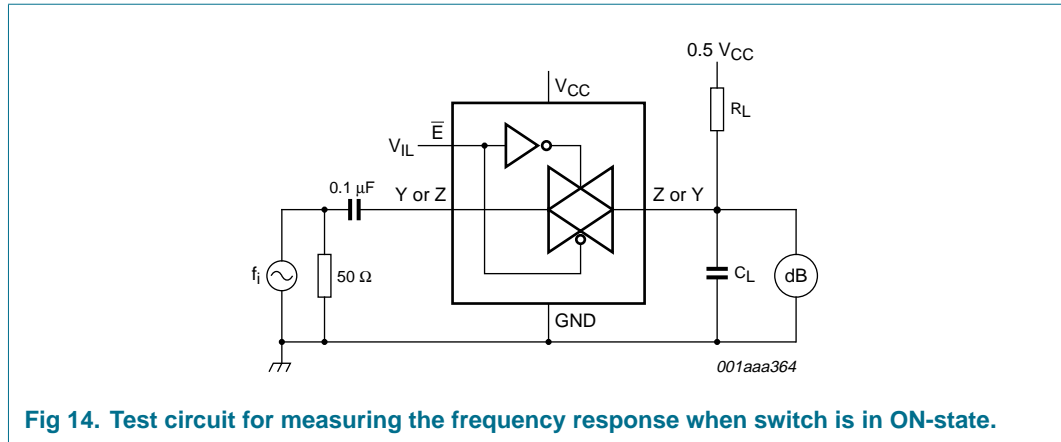


Fig 14. Test circuit for measuring the frequency response when switch is in ON-state.

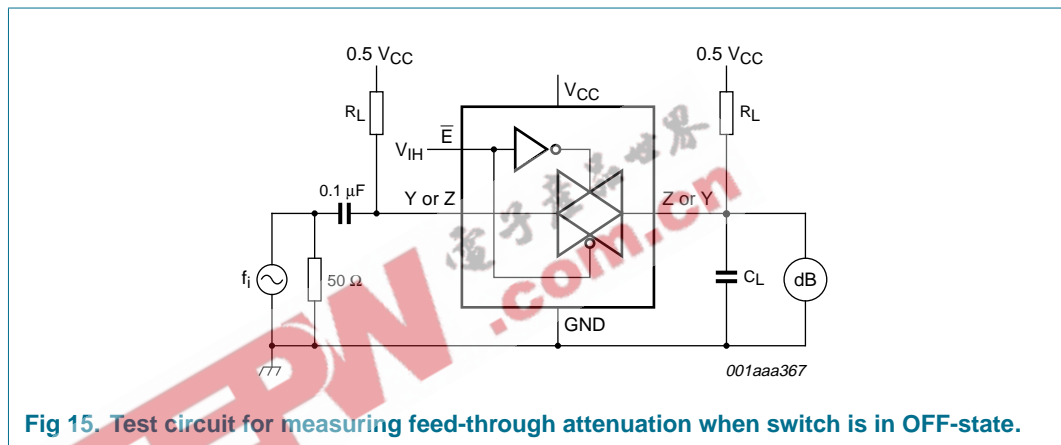


Fig 15. Test circuit for measuring feed-through attenuation when switch is in OFF-state.

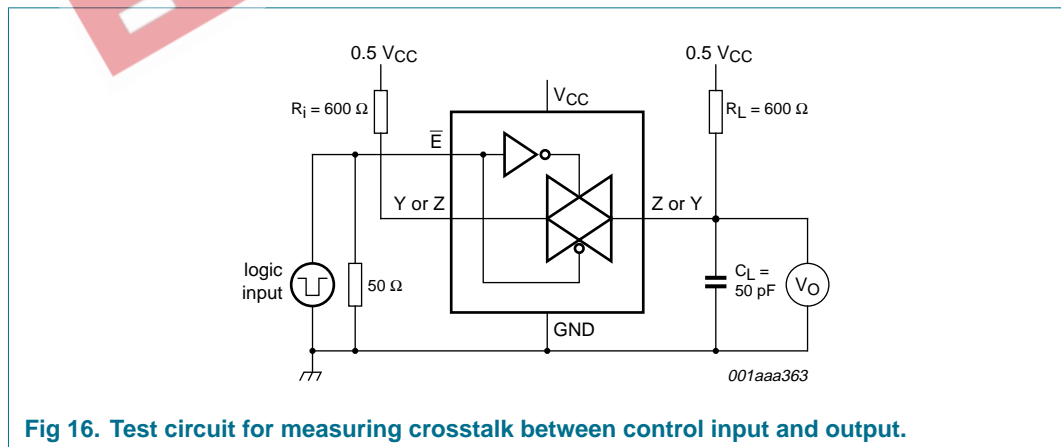


Fig 16. Test circuit for measuring crosstalk between control input and output.

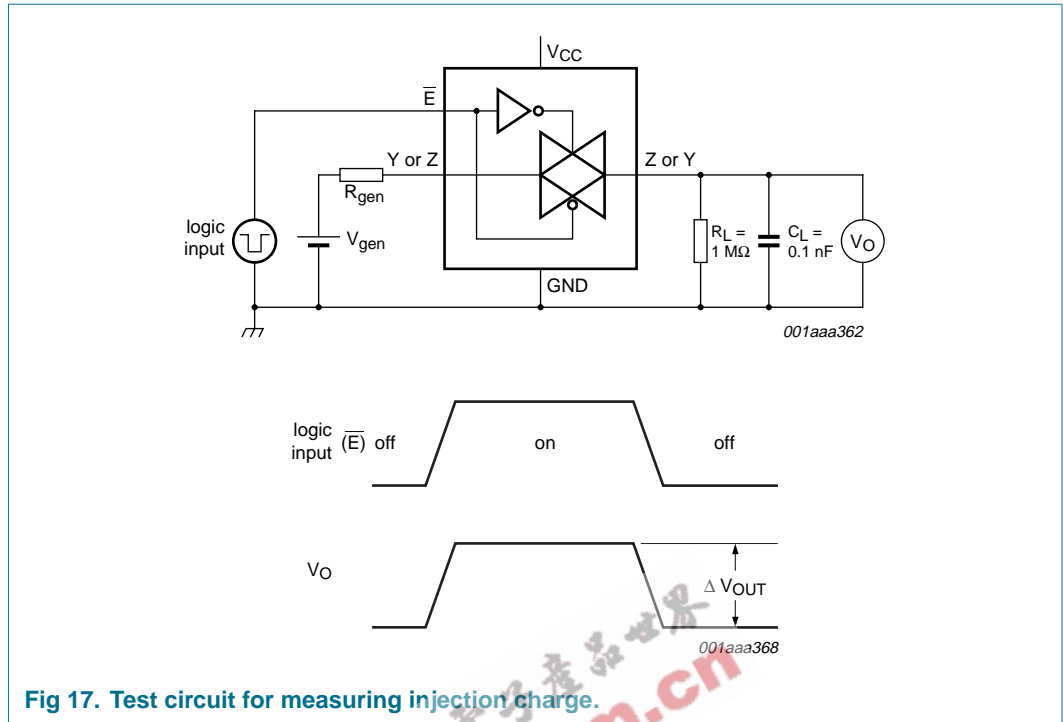


Fig 17. Test circuit for measuring injection charge.

15. Package outline

Plastic surface mounted package; 5 leads

SOT353

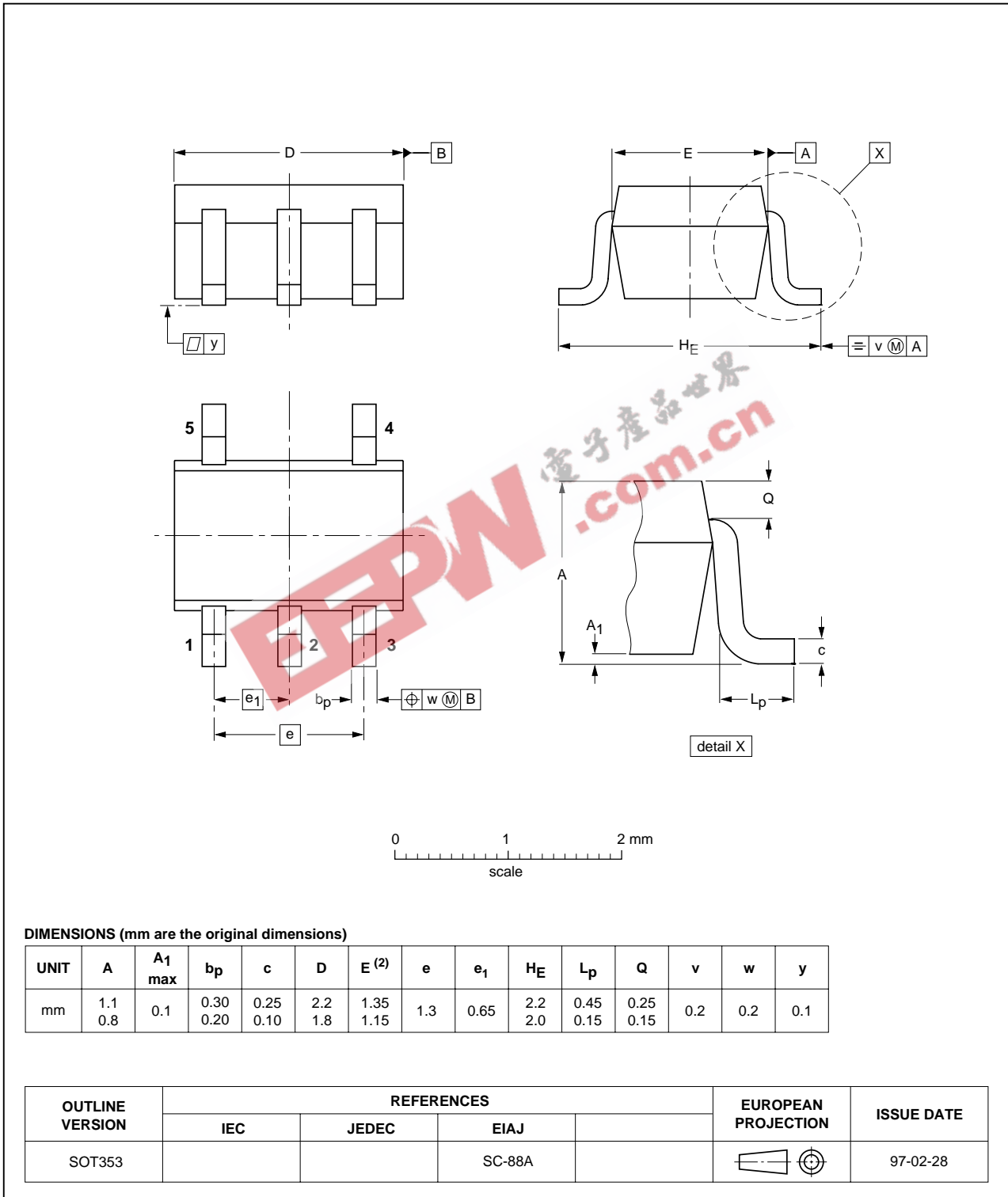


Fig 18. Package outline SOT353.

Plastic surface mounted package; 5 leads

SOT753

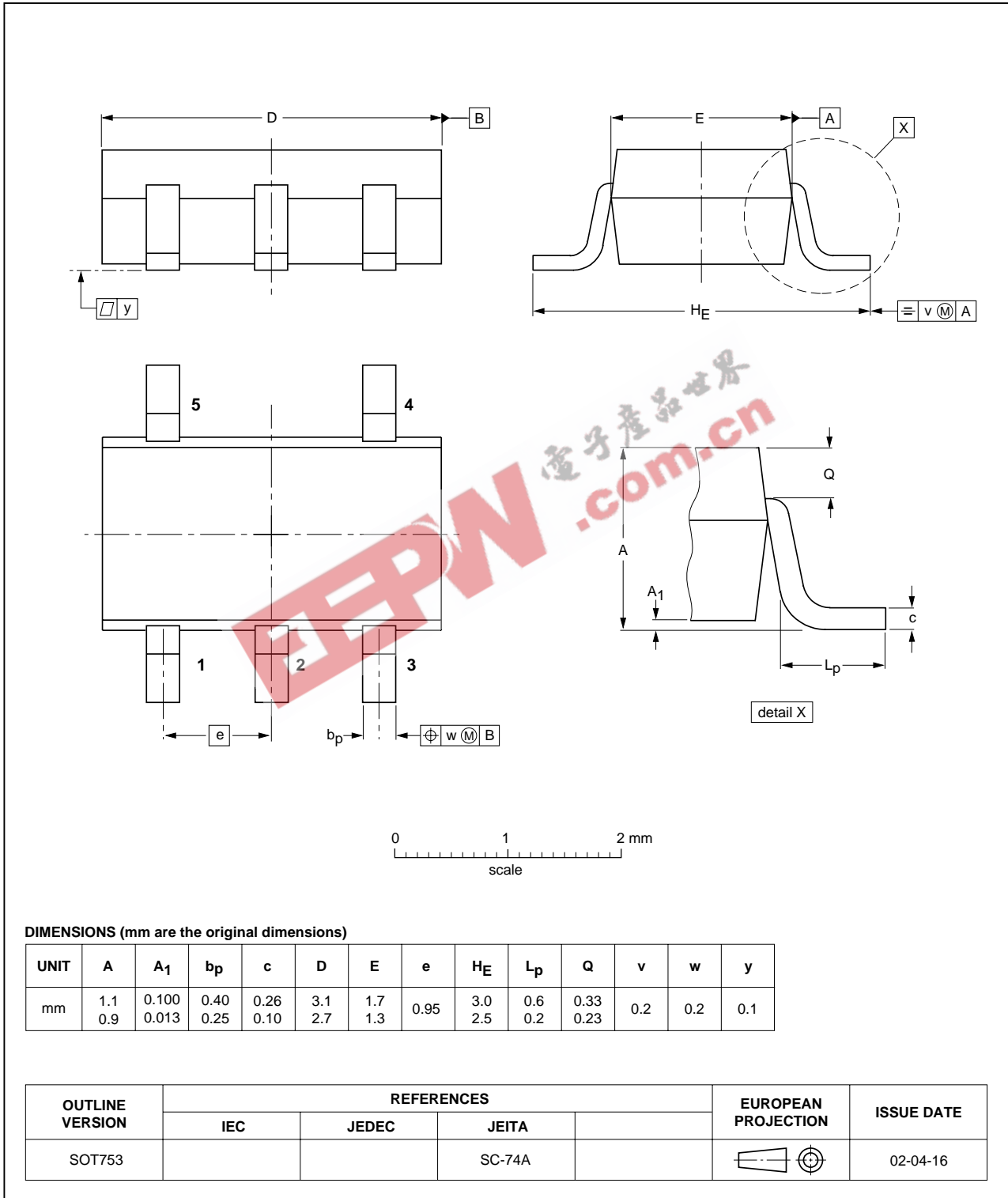


Fig 19. Package outline SOT753.

16. Revision history

Table 14: Revision history

| Document ID | Release date | Data sheet status | Change notice | Order number | Supersedes |
|--------------|--------------|-------------------|---------------|----------------|------------|
| 74LVC1G384_1 | 20040226 | Product data | - | 9397 750 12675 | - |

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